

Hierarchical porous $\text{Cu}_2\text{ZnSnS}_4$ film for high-capacity reversible lithium storage application

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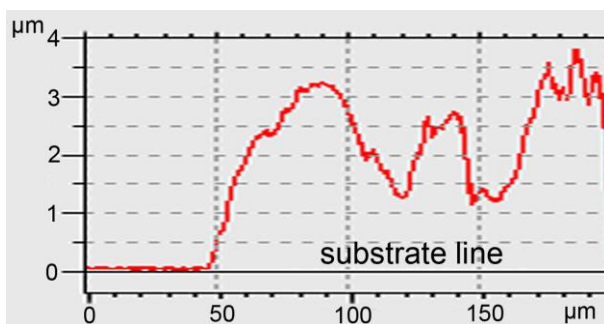


Figure S1. Step profiling of the porous CZTS film.

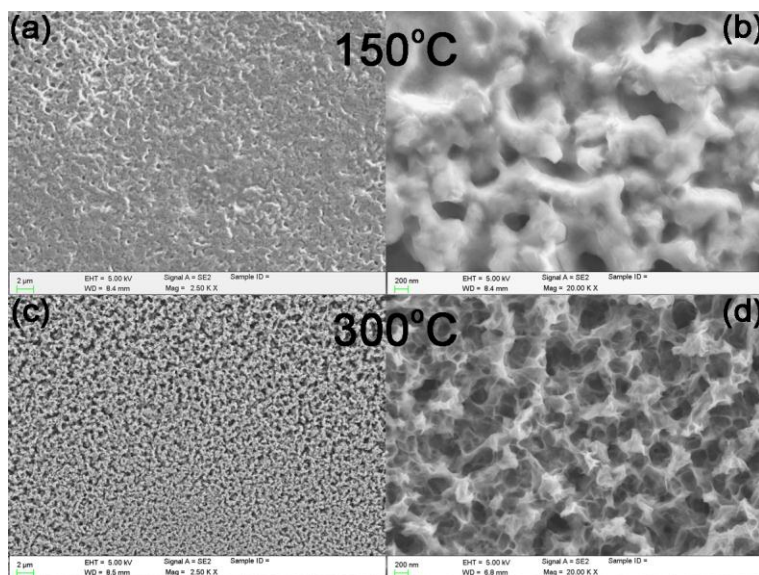


Figure S2. (a) Low magnification and (b) high magnification SEM images of CZTS thin film prepared at 150°C, and (c) Low magnification and (d) high magnification SEM images of CZTS thin film annealed at 300°C.

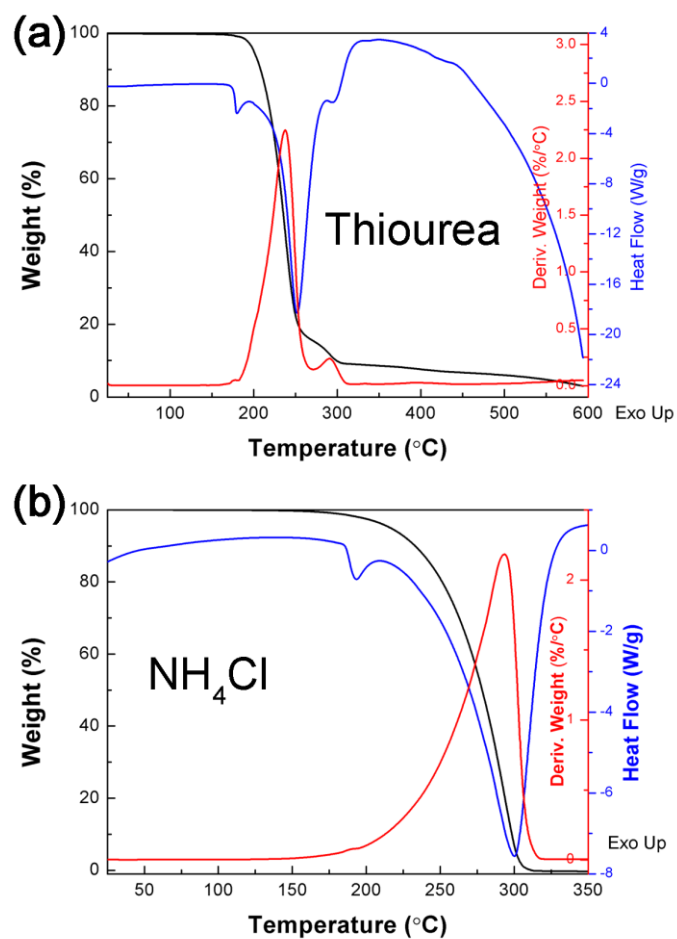


Figure S3. TGA and DSC analysis of (a) thiourea, (b) NH₄Cl, (c) precursor annealed at 200°C and (d) precursor annealed at 300°C in N₂ flow with a heating rate of 10°C/min.

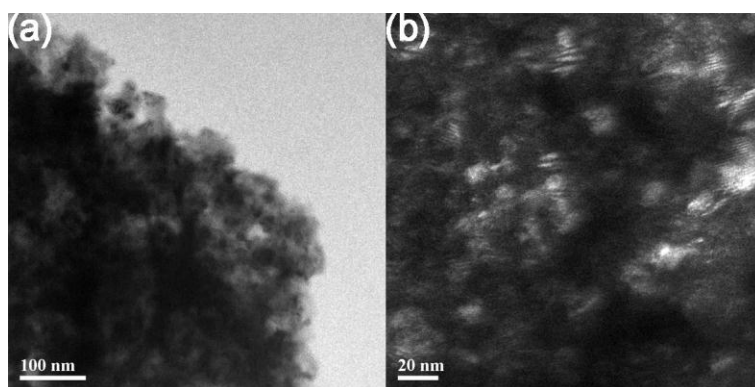


Figure S4. (a) Bright field and (b) dark field TEM images of porous CZTS layer